



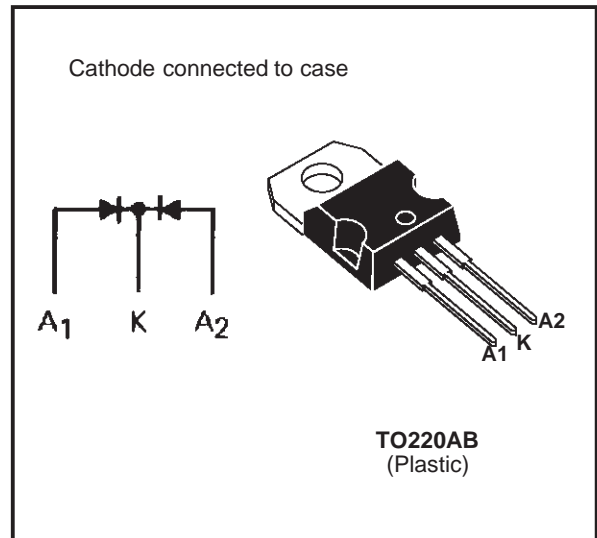
BYT 16P- 400

FAST RECOVERY RECTIFIER DIODES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING

SUITABLE APPLICATIONS

- The BYT 16 P can be used:



ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter		Value	Unit
I_{FRM}	Repetive Peak Forward Current	$t_p \leq 10\mu s$	130	A
$I_{F(RMS)}$	RMS Forward Current		30	A
$I_{F(AV)}$	Average Forward Current	$T_{case} = 100^\circ C$ $\delta = 0.5$	16	A
I_{FSM}	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	100	A
P	Power Dissipation	$T_{case} = 100^\circ C$	25	W
T_{stg} T_j	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150	$^\circ C$

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage	400	V
V_{RSM}	Non Repetitive Peak Reverse Voltage	440	V

THERMAL RESISTANCE

Symbol	Test Conditions		Value	Unit
$R_{th(j-c)}$	Junction-case	per leg total	3.75 2	$^\circ C/W$
$R_{th(c)}$	Coupling		0.25	$^\circ C/W$

BYT 16P-400

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I_R	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			15	μA
	$T_j = 100^\circ\text{C}$				2.5	mA
V_F	$T_j = 25^\circ\text{C}$	$I_F = 8\text{A}$			1.5	V
	$T_j = 100^\circ\text{C}$				1.4	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t_{rr}	$T_j = 25^\circ\text{C}$	$I_F = 1\text{A}$	$di_F/dt = -15\text{A}/\mu\text{s}$	$V_R = 30\text{V}$		75	ns
		$I_F = 0.5\text{A}$	$I_R = 1\text{A}$	$I_{rr} = 0.25\text{A}$		35	

TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
t_{RM}	$di_F/dt = -32\text{A}/\mu\text{s}$	$V_{CC} = 200\text{V}$ $I_F = 8\text{A}$ $L_p \leq 0.05\mu\text{H}$ $T_j = 100^\circ\text{C}$ See figure 11			75	ns
	$di_F/dt = -64\text{A}/\mu\text{s}$			50		
I_{RM}	$di_F/dt = -32\text{A}/\mu\text{s}$				2.2	A
	$di_F/dt = -64\text{A}/\mu\text{s}$			2.8		

TURN-OFF OVERVOLTAGE COEFFICIENT (With Series Inductance)

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^\circ\text{C}$ $di_F/dt = -8\text{A}/\mu\text{s}$	$V_{CC} = 120\text{V}$ $L_p = 9\mu\text{H}$	$I_F = I_{F(AV)}$ See note See figure 12		3.3		

Note : Applicable to BYT 16P-400 only

To evaluate the conduction losses use the following equations:

$$V_F = 1.1 + 0.024 I_F$$

$$P = 1.1 \times I_{F(AV)} + 0.024 I_{F(RMS)}^2 \text{ (1 leg)}$$

$$P = 1.1 \times I_{F(AV)} + 0.012 I_{F(RMS)}^2 \text{ (2 legs)}$$

Figure 1. Low frequency power losses versus average current

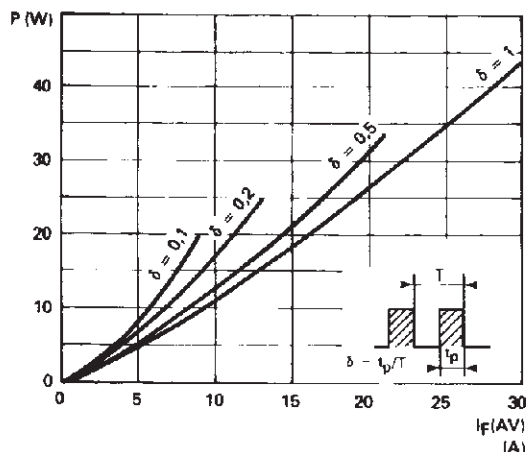


Figure 2. Peak current versus form factor

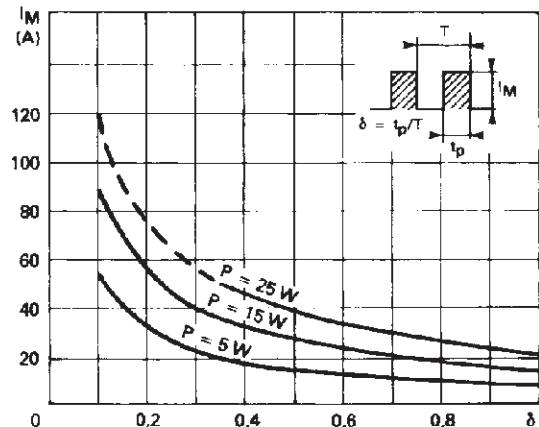


Figure 3. Non repetitive peak surge current versus overload duration

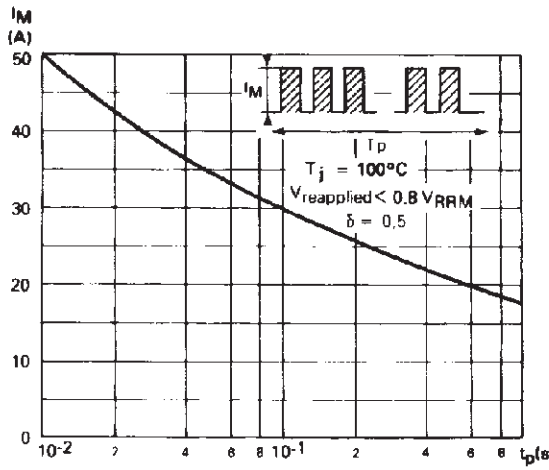


Figure 5. Voltage drop versus forward current

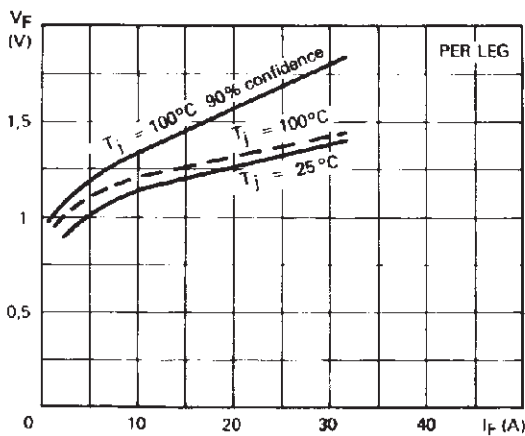


Figure 7. Recovery time versus di_F/dt

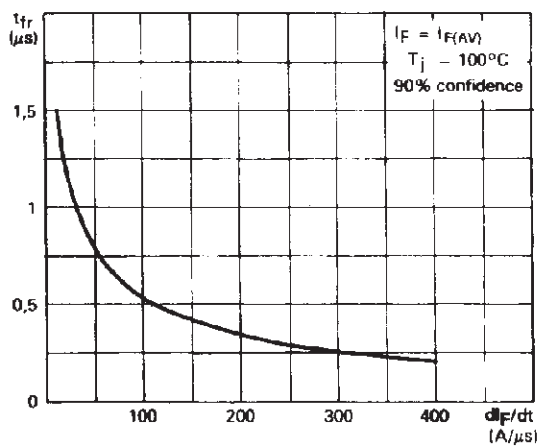


Figure 4. Thermal impedance versus pulse width

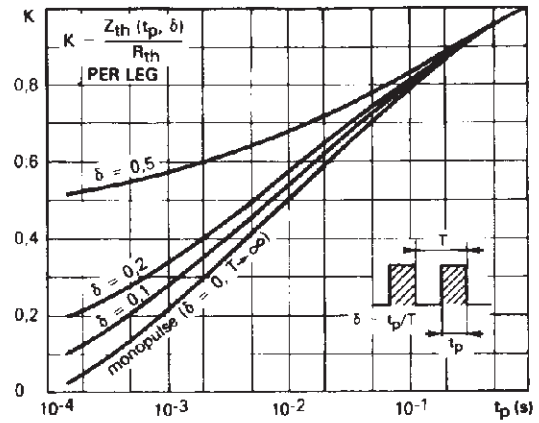


Figure 6. Recovery charge versus di_F/dt

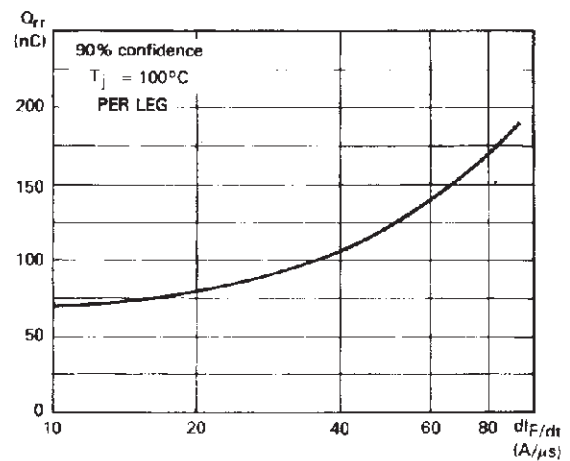


Figure 8. Peak reverse current versus di_F/dt

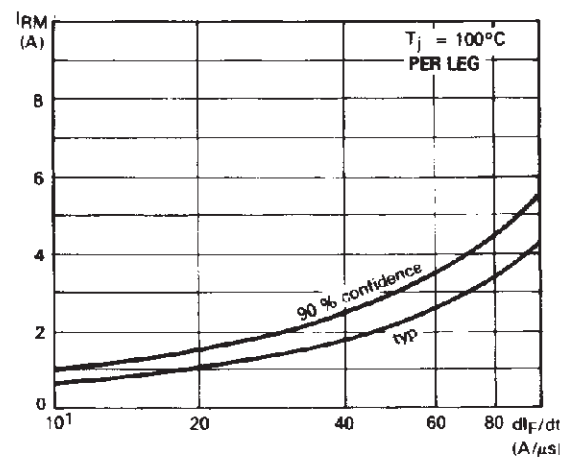


Figure 9. Peak forward voltage versus di_F/dt .

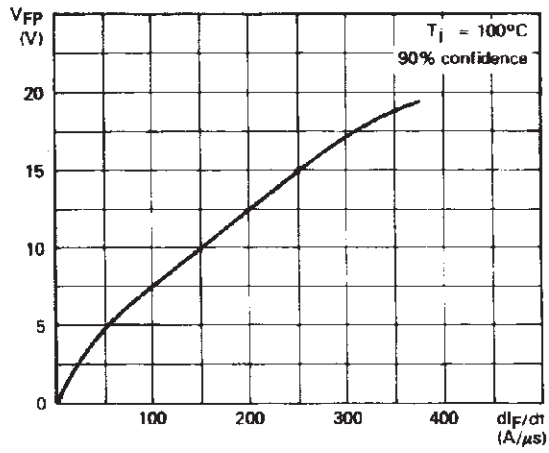


Figure 10. Dynamic parameters versus junction temperature.

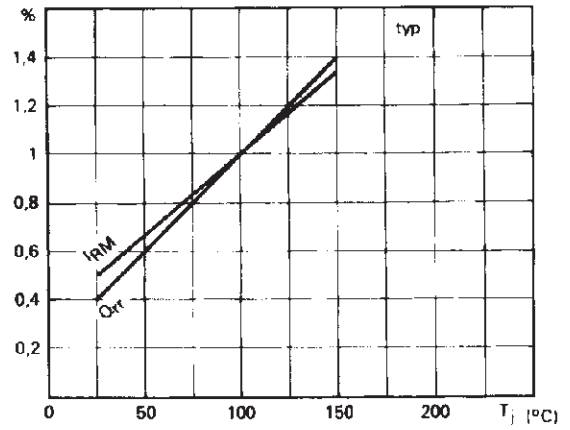


Figure 11. Turn-off switching characteristics (without series inductance).

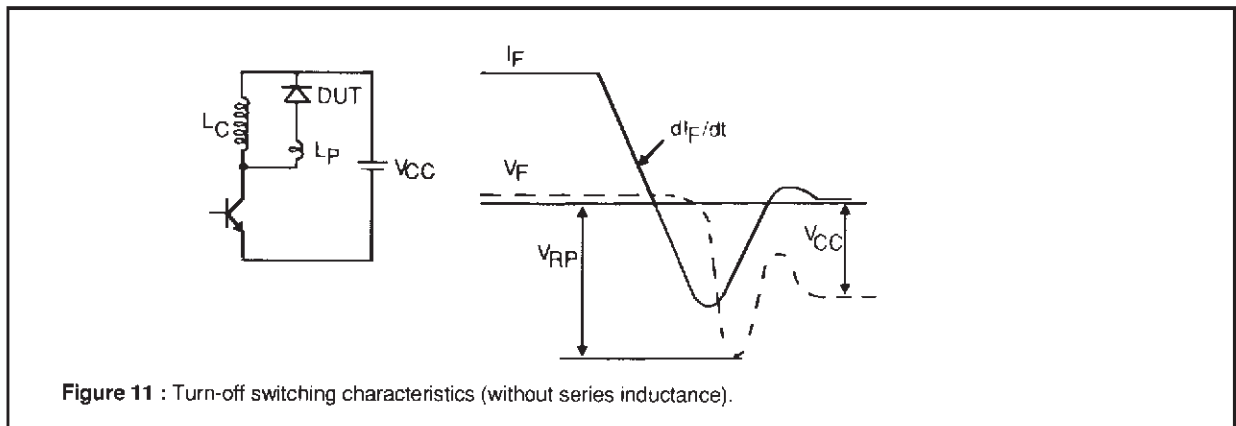
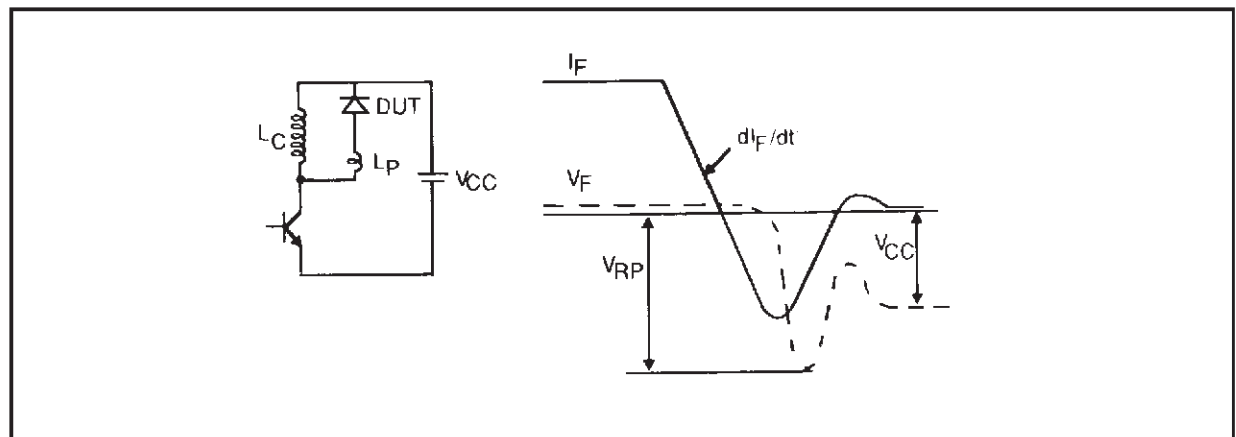
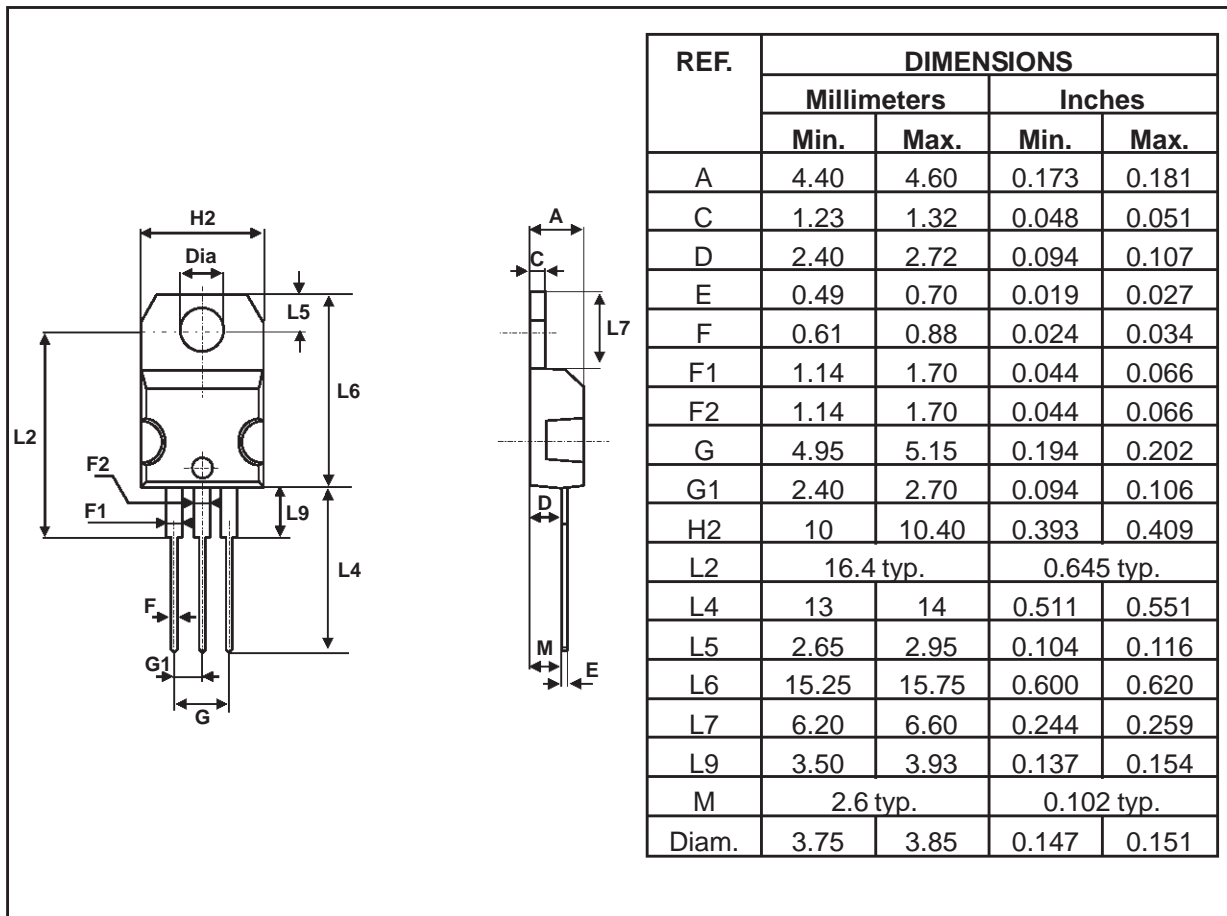


Figure 11 : Turn-off switching characteristics (without series inductance).

Figure 12. Turn-off switching characteristics (without series inductance)



PACKAGE MECHANICAL DATA :
TO 220 AB Plastic



- **Marking:** type number
- **Cooling method:** by conduction (method C)
- **Weight:** 2.23g

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